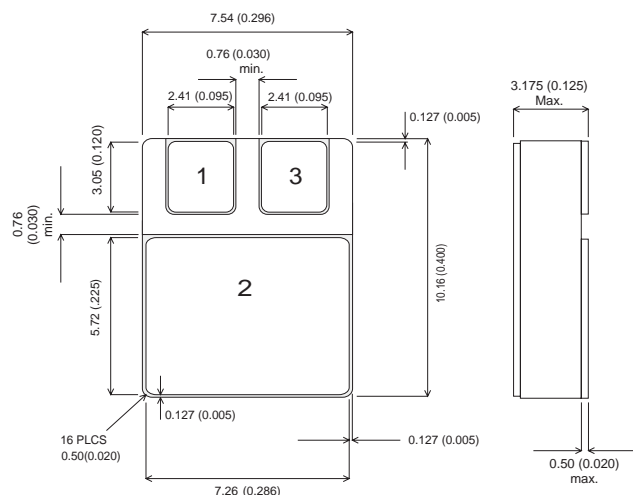


## MECHANICAL DATA

Dimensions in mm (inches)



### SMD05 (TO-276AA)

Underside View

PAD 1 = Base    PAD 2 = Collector    PAD = 3 – Emitter

## PNP BIPOLAR TRANSISTOR IN A CERAMIC SURFACE MOUNT PACKAGE FOR HIGH-REL AND SPACE APPLICATIONS

### DESCRIPTION

The 2N5151XSMD05 is a silicon epitaxial planar PNP transistor in a Ceramic Surface Mount Package for use in Switching and Linear applications.

### ABSOLUTE MAXIMUM RATINGS $T_{CASE} = 25^{\circ}C$ unless otherwise stated

$V_{CBO}$	Collector – Base Voltage	-100V
$V_{CEO}$	Collector – Emitter Voltage ( $I_B = 0$ )	-80V
$V_{EBO}$	Emitter – Base Voltage ( $I_C = 0$ )	-5.5V
$I_C$	Continuous Collector Current	-5A
$I_{C(PK)}$	Peak Collector Current	-10A
$I_B$	Base Current	-2.5A
$P_{tot}$	Total Dissipation at $T_{amb} = 25^{\circ}C$	1W
	$T_{case} = 25^{\circ}C$	100W
$T_{stg}$	Operating and Storage Temperature Range	-65 to +200°C
$T_j$	Junction temperature	200°C

Semelab Plc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.

**ELECTRICAL CHARACTERISTICS** ( $T_{case} = 25^{\circ}C$  unless otherwise stated)

Parameter		Test Conditions	Min.	Typ.	Max.	Unit
$I_{CES}$	Collector Cut Off Current	$V_{CE} = -60V$ $V_{BE} = 0$			-1	$\mu A$
		$V_{CE} = -100V$ $V_{BE} = 0$			-1	mA
$I_{CEV}$	Collector Cut Off Current	$V_{CE} = -60V$ $T_{case} = 150^{\circ}C$ $V_{BE} = 2V$			-500	$\mu A$
$I_{CEO}$	Collector Cut Off Current	$V_{CE} = -40V$ $I_B = 0$			-50	
$I_{EBO}$	Emitter Cut Off Current	$V_{EB} = -4V$ $I_C = 0$			-1	$\mu A$
		$V_{EB} = -5.5V$ $I_C = 0$			-1	mA
$V_{CEO(SUS)}$	Collector Emitter Saturation Voltage	$I_C = -100mA$ $I_B = 0$	-80			
$V_{CE(sat)}$	Collector Emitter Saturation Voltage	$I_C = -2.5A$ $I_B = -250mA$			-0.75	V
		$I_C = -5A$ $I_B = -500mA$			-1.5	
$V_{BE(sat)}$	Base Emitter Saturation Voltage	$I_C = -2.5A$ $I_B = -250mA$			-1.45	
		$I_C = -5A$ $I_B = -500mA$			-2.2	
$V_{BE}$	Base Emitter Voltage	$I_C = -2.5A$ $V_{CE} = -5V$			-1.45	
$h_{FE}$	DC Current Gain	$I_C = -50mA$ $V_{CE} = -5V$	20			—
		$I_C = -2.5A$ $V_{CE} = -5V$	30		105	
		$I_C = -5A$ $V_{CE} = -5V$	20			
		$I_C = 2.5A$ $V_{CE} = -5V$ $T_{case} = -55^{\circ}C$	15			
$C_{CBO}$	Collector Base Capacitance	$I_E = 0$ $V_{CB} = -10V$ $f = 1MHz$			250	pF
$h_{FE}$	Small Signal Current Gain	$I_C = -0.1A$ $V_{CE} = -5V$ $f = 1KHz$	20			—
		$I_C = -0.5A$ $V_{CE} = -5V$ $f = 20MHz$	3			
$t_{on}$	Turn On Time	$I_C = -5A$ $V_{CC} = 30V$ $I_{B1} = -0.5A$		0.5		$\mu s$
$t_{off}$	Turn Off Time	$I_C = -5A$ $V_{CC} = 30V$ $I_{B1} = -I_{B2} = 0.5A$		1.3		$\mu s$

\* Pulse test  $t_p = 300\mu s$ ,  $\delta < 2\%$

**THERMAL DATA**

$R_{thj-case}$	Thermal Resistance Junction-case	Max	1.75	$^{\circ}C/W$
$R_{thj-amb}$	Thermal Resistance Junction-ambient	Max	150	$^{\circ}C/W$

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